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# (Im-?)possible prediction of performance change of coated conductors in fusion magnets

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## Motivation

- Is a prediction of the behavior of a superconducting magnet in a radiation environment possible?
- What is needed?
- Stimulation of the respective discussion at IREF.

## How should we aim to predict the changes?

- Experiments? Modelling? A combination of both? Defect structure?
- (Defining benchmarking experiments (validating models), available facilities,.....)

## Enhanced pinning versus decreased superfluid density

- Favorable increase in flux pinning („large defects“)
- Harmful suppression of superfluid density („small defects“)

## Conclusions



# Collaborations and Funding

**Raphael Unterrainer, Alexander Bodenseher**

**David Fischer** MIT (proton irradiation)

**Daniele Torsello, Francesco Laviano** Politecnico di Torino  
(radiation environment, damage calculations)

**Davide Gambino** Linköping University (MD calculations)

**Ruben Hühne** IFW Dresden (thin film preparation)



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Funded by the  
European Union



Envisaged application in a radiation environment

Re-design  
(e.g. addition of a screen)

?????

Prediction of changes in properties



# 1<sup>st</sup> step: definition of the radiation field

Envisaged  
application

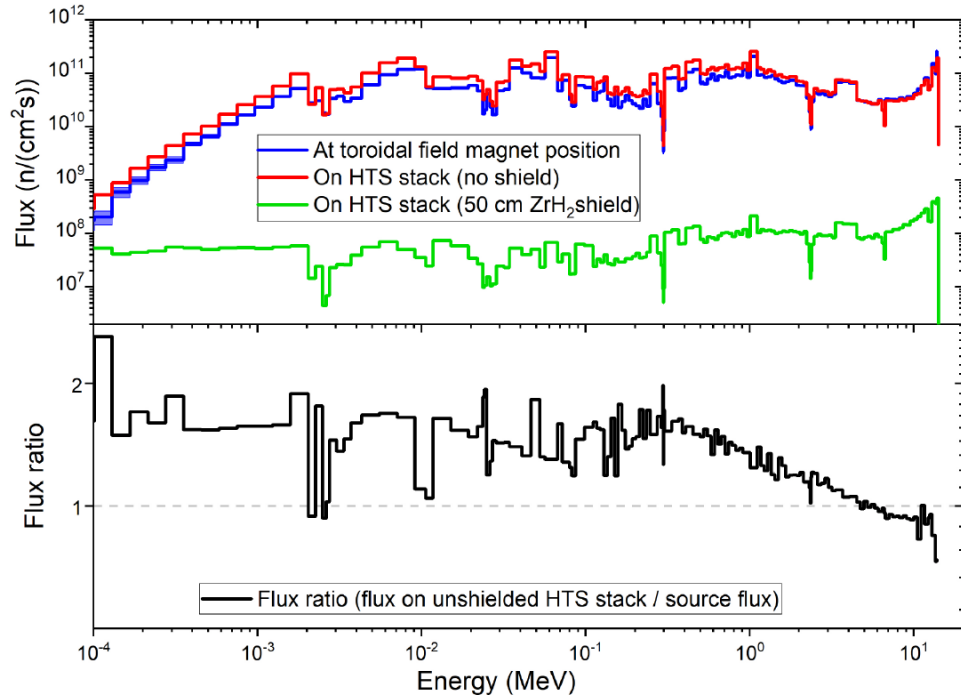


Expected  
radiation  
environment

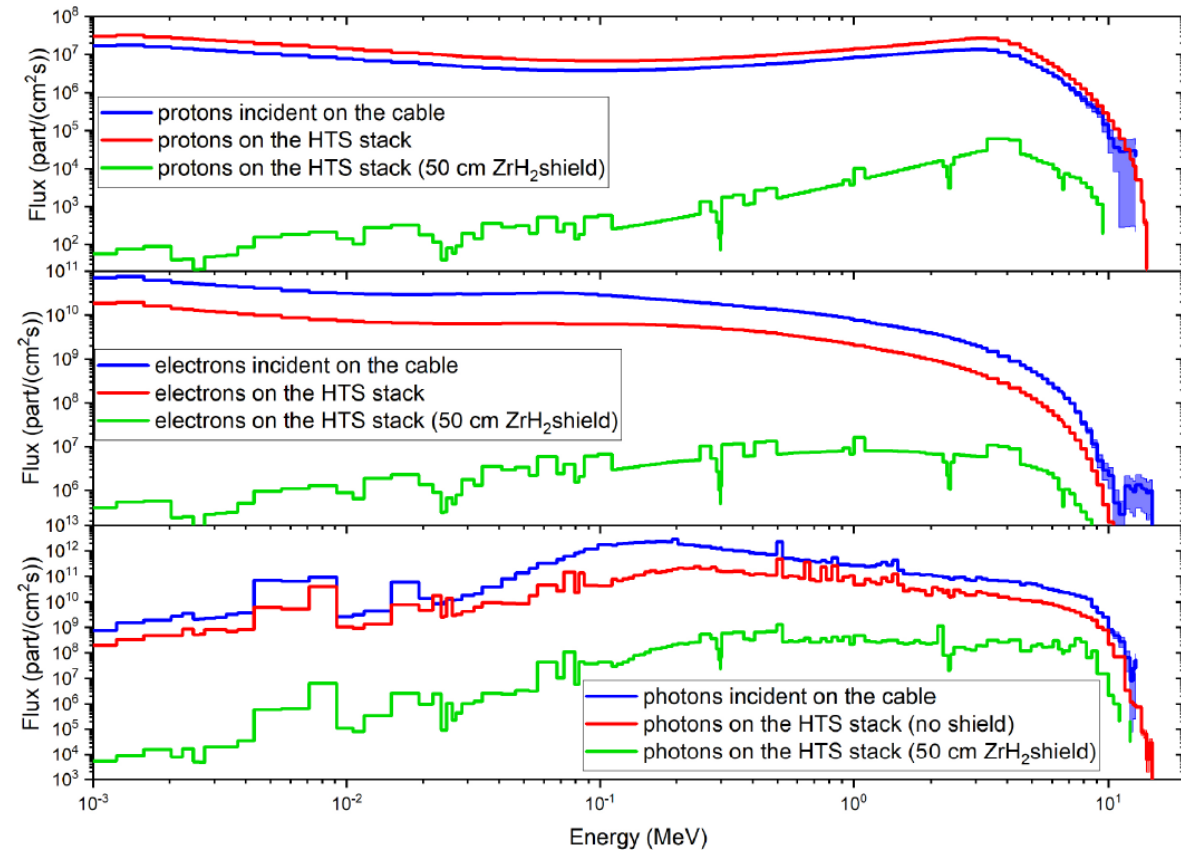
**Sufficient modelling tools available(?)**



## Neutrons



## Protons, Electrons, Photons



F. Ledda et al., IEEE TAS 34 (2024) 4206105

Different particles, energies ranging from ~100 eV to ~15 MeV



# Predicting the property changes

Experimental

Expected radiation  
environment

Modelling

Critical current at  
operation conditions:

- Field
- Temperature
- Strain
- ....

Experimental  
+  
Modelling



## Ideal experiment



**Real world:** expected radiation environment is not available for experiments.  
Much higher flux is required.

- Finding a proxy is necessary.
- Similar (?!) defect structure
  - All particles (neutrons, protons,...)
  - All energies (100 eV to 15 MeV)

Finding a proxy to  
create a defect  
structure you don't  
know?



## Direct approach

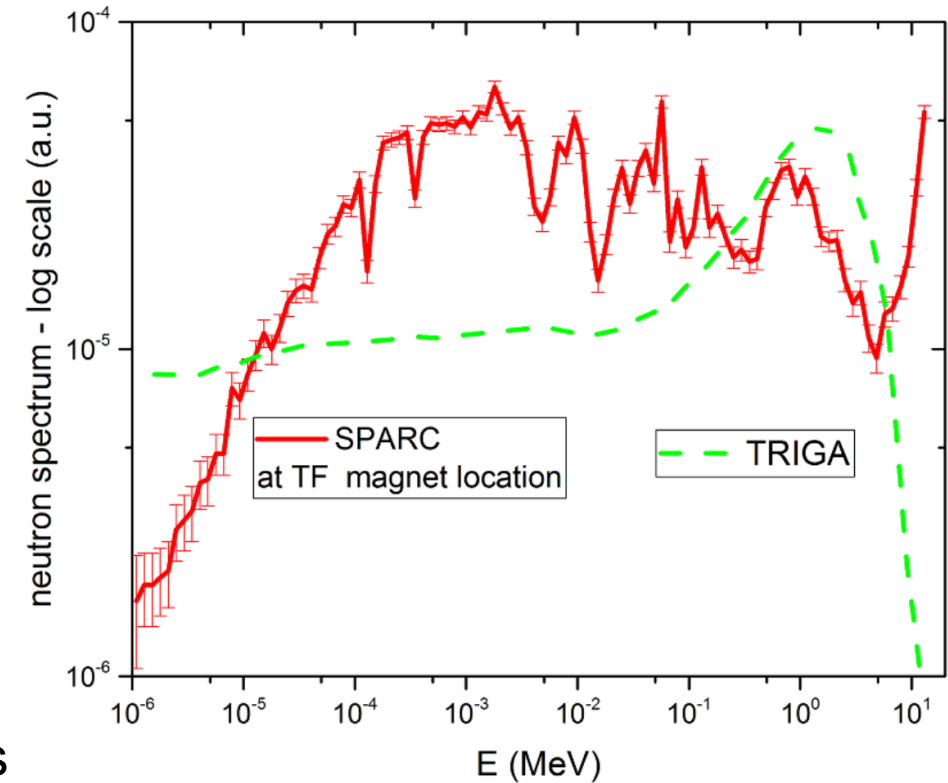
Irradiate the same sample with all particles and at representative energy groups



Measure properties

- Same resulting defect structure as for simultaneous irradiation?
- Keeping the sample cold at all steps?
- Redo for different conductors and particle spectra!

Fast neutrons (likely) don't do the job alone!



D. Torsello et al., SuST 37 (2024) 105008



For all relevant particles and representative energies:

Cryogenic irradiation



Determination of microstructure  
(low temperature, small defects?)

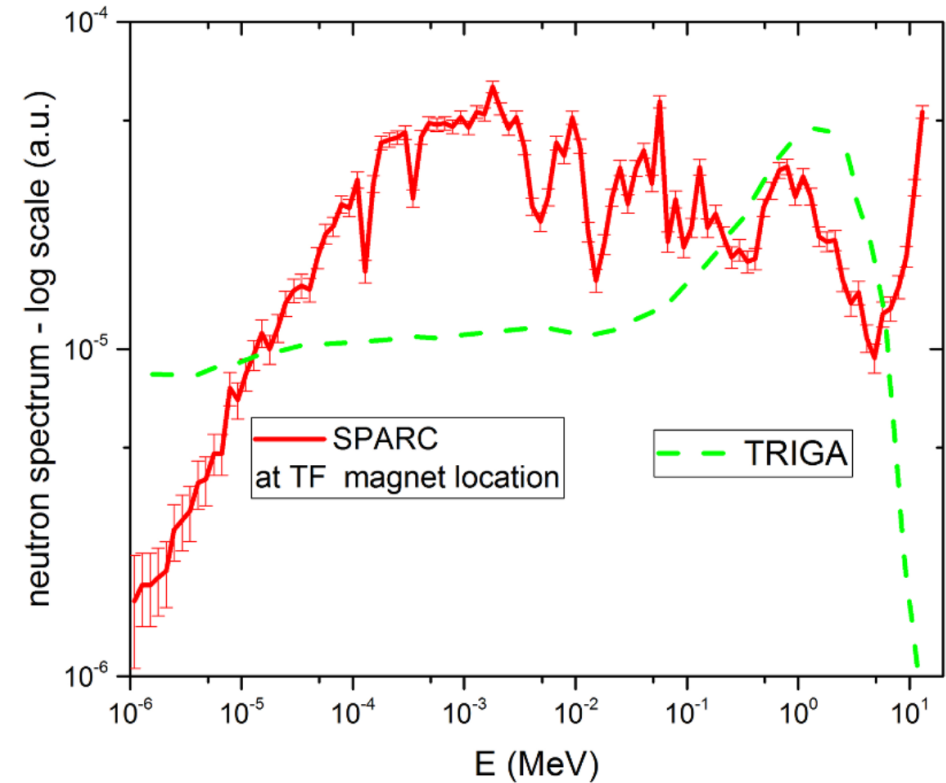


Add the defects according  
to their contribution



Chose a combination of particles/energies/fluence as a proxy to mimic this defect structure.

Fast neutrons (likely) don't do the job alone!



D. Torsello et al., SuST 37 (2024) 105008



For all relevant particles and representative energies:

Cryogenic irradiation



Assess property changes

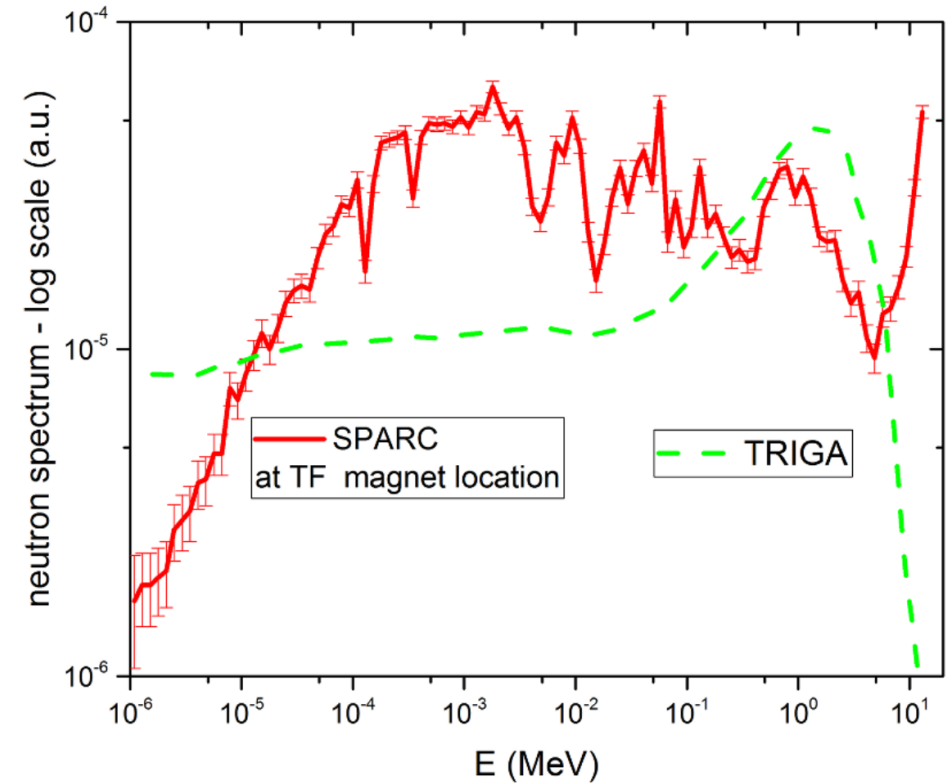


Add the effect of all particles



Chose a combination of particles/energies/fluence as a proxy to mimic these changes.

Fast neutrons (likely) don't do the job alone!



D. Torsello et al., SuST 37 (2024) 105008



# Finding a proxy

For all relevant particles and representative energies:

Cryogenic irradiation



Assess property changes

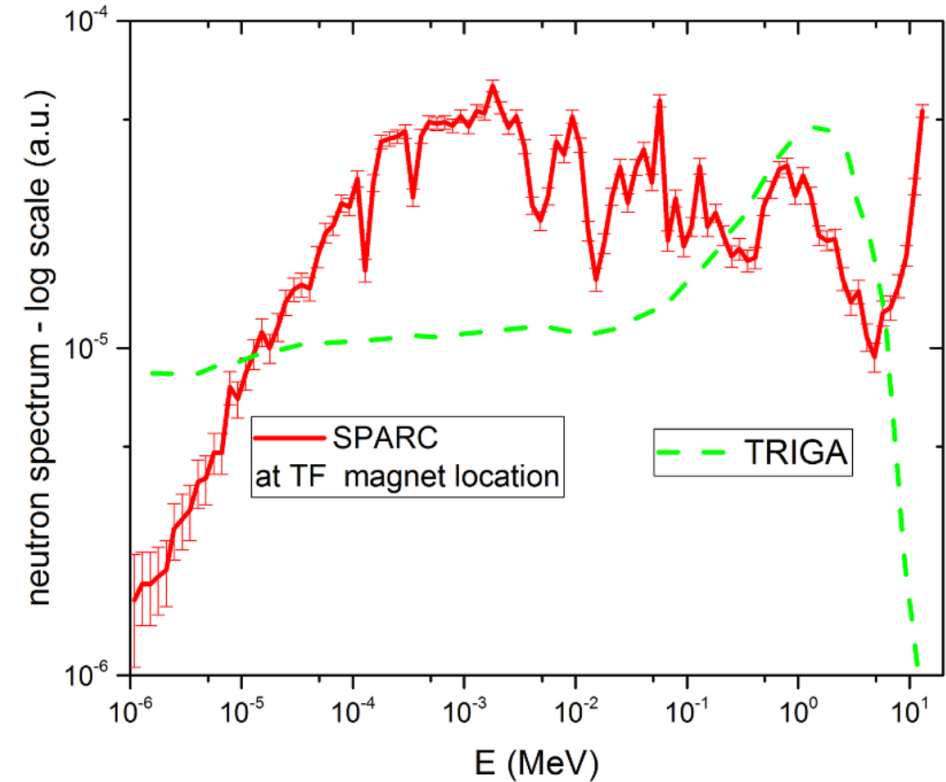


Add the effect of all particles



Chose a combination of particles/energies/fluence as a proxy to mimic these changes.

Fast neutrons (likely) don't do the job alone!



D. Torsello et al., SuST 37 (2024) 105008



# The modelling path

## Microstructure

Damage (dpa): PHITS, FLUKA



Defect structure: molecular dynamics



## Basic superconducting properties

$T_c$ : ???

$\lambda, \xi$ : ???



## Critical current density

Time dependent Ginzburg Landau theory (TDGL)



# The experimental/modelling path

- Experiments can add missing links  
e.g. dpa  $\rightarrow$   $\Delta T_c$

Radiation environment

Monte Carlo

Damage (dpa)

Experiment

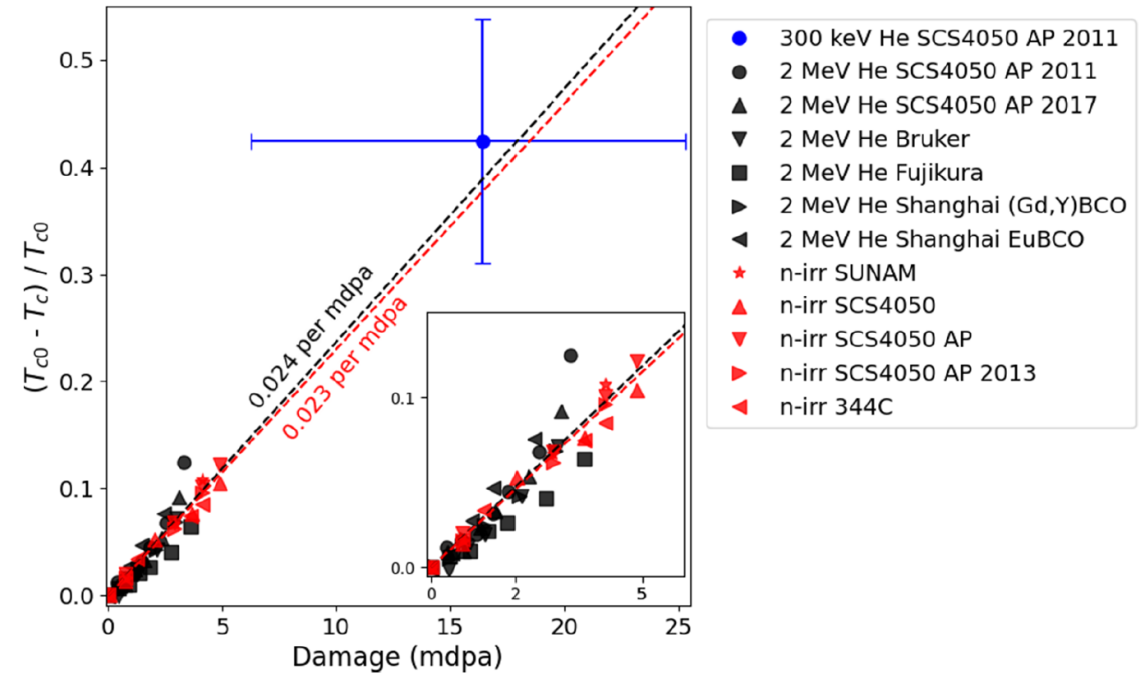
$\Delta T_c \rightarrow \lambda, \xi$

Molecular Dynamics

Defect structure

Time dependent Ginzburg Landau theory

Critical current density



K. Adams et al., SuST **36** (2023) 10LT01

- Fundamental understanding of the underlying physics is required

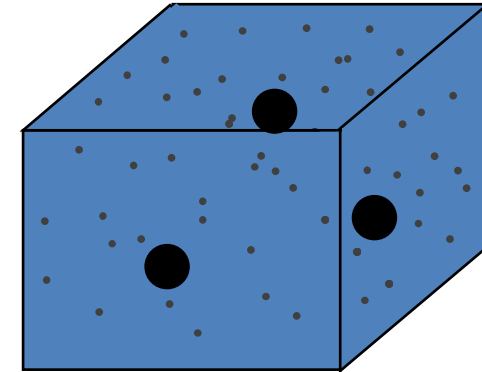


# Disordering matter by radiation

## Radiation effects on superconductors



- **Defect**
  - Anything that breaks translation symmetry of the lattice
- **Small defect**
  - Much smaller than the coherence length of the superconductor ( $\sim 1.5$  nm)
  - Voids, interstitials, Frenkel pairs, antisite defects...
  - Do not reduce the order parameter to 0.
- **Large defect**
  - Larger than the coherence length.
  - Non-superconducting volume
- **Disorder**
  - Small defects in the superconducting matrix



**Any** defect breaks translational symmetry of the crystal lattice  
→ scattering of charge carriers

- Decrease in mean free time  $\tau$
- Increase in scattering rate  $\tau^{-1}$
- Decrease in mean free path  $l = v_F \tau$
- Increase in normal state resistivity  $\rho_n = \frac{m_e v_F}{n e^2 l} = \frac{m_e}{n e^2 \tau}$

$v_F$ ... Fermi velocity

$m_e$ ... mass of charge carriers

$n$ ... density of charge carriers

$e$ ... elementary charge



Three important fundamental parameters:

- Transition temperature,  $T_c$

- Magnetic penetration depth,  $\lambda$ :

Characteristic length for changes of the magnetic field

- Superconducting coherence length,  $\xi$

Characteristic length for changes of the superconducting order parameter

Other parameters can be calculated from thermodynamics:

Ginzburg-Landau theory:

- Condensation energy density:  $E_c = \frac{\phi_0^2}{16\pi^2\mu_0\lambda^2\xi^2}$
- Upper critical field:  $B_{c2} = \frac{\phi_0}{2\pi\xi^2}$



# Relation to basic material properties

London theory (basic **electrodynamics** for  $\rho = 0$ )

Shielding of an applied field,  $B_a$ , because of induction

$$B = B_a e^{-\frac{x}{\lambda_L}}, \quad \lambda_L = \sqrt{\frac{m_e}{\mu_0 n e^2}} \quad (\text{clean superconductors})$$

General: superfluid density  $n_s \propto \frac{m_e}{\lambda^2}$ ,  $\lambda = \sqrt{\frac{m_e}{\mu_0 n_s e^2}}$

## Uncertainty principle

Space-Momentum:  $\delta x \delta p \geq \frac{\hbar}{2}$ ,  $\delta x \delta k \geq \frac{1}{2}$

$$v_g = \frac{\partial \omega}{\partial k} = \frac{1}{\hbar} \frac{\partial E}{\partial k} \rightarrow \delta k = \frac{\partial k}{\partial E} \delta E = \frac{\delta E}{\hbar v_g} \rightarrow \delta x \geq \frac{\hbar v_F}{4\Delta}$$

Energy-Time:  $\delta E \delta t \geq \frac{\hbar}{2}$ :  $\tau_{sc} \geq \frac{\hbar}{4\Delta} \rightarrow \delta x \approx v_F \tau_{sc} = \frac{\hbar v_F}{4\Delta}$   
 ( $\tau$  shortend by scattering)

## Thermodynamics

Energy needed to excite a superconducting electron:  $2\Delta \approx k_B T_c \rightarrow \delta x \approx \xi_0 \propto \frac{v_F}{T_c}$

(experimental values available)

## BCS theory

$$\xi_0 = \frac{\hbar v_F}{\pi \Delta} = 0.18 \frac{\hbar v_F}{k_B T_c}$$

$$\Delta = 1.764 T_c$$



# Scattering in conventional (s-wave) superconductors

(Non-magnetic) Scattering is not pair breaking in isotropic conventional superconductors.

→ Transition temperature does not change.

→ Condensation energy:  $E_c = \frac{\phi_0^2}{16\pi^2\mu_0\lambda^2\xi^2}$  does not change.

- Superconducting coherence length decreases:  $\xi = \frac{\xi_0}{\sqrt{1 + \frac{\xi_0}{l}}}$  ( $\approx \sqrt{\xi_0 l}$ )

- Magnetic penetration depth increases:  $\lambda = \sqrt{\frac{m_e}{\mu_0 n_s e^2}} = \lambda_L \sqrt{1 + \frac{\xi_0}{l}}$

→ Superfluid density  $n_s \propto \frac{1}{\lambda^2}$  is reduced.

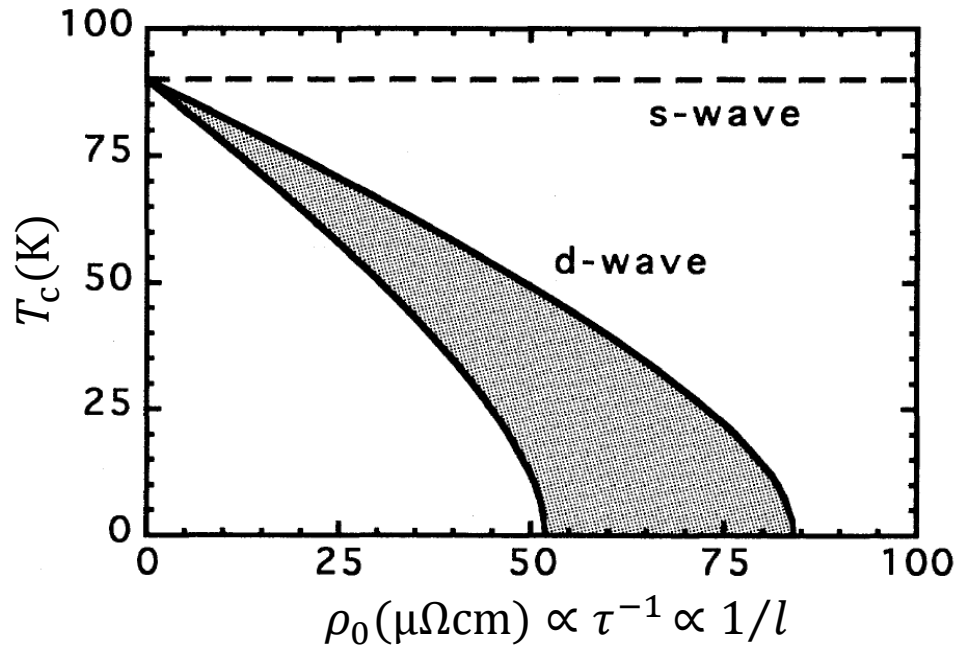
Impurity parameter  $\alpha := \frac{\xi_0}{l}$ , clean limit:  $\alpha \ll 1$ , dirty limit:  $\alpha \gg 1$

- Depairing current density decreases:  $J_d(D) = \frac{\phi_0}{3\sqrt{3}\mu_0\pi\lambda_L^2\xi_0\sqrt{1+\alpha}}$

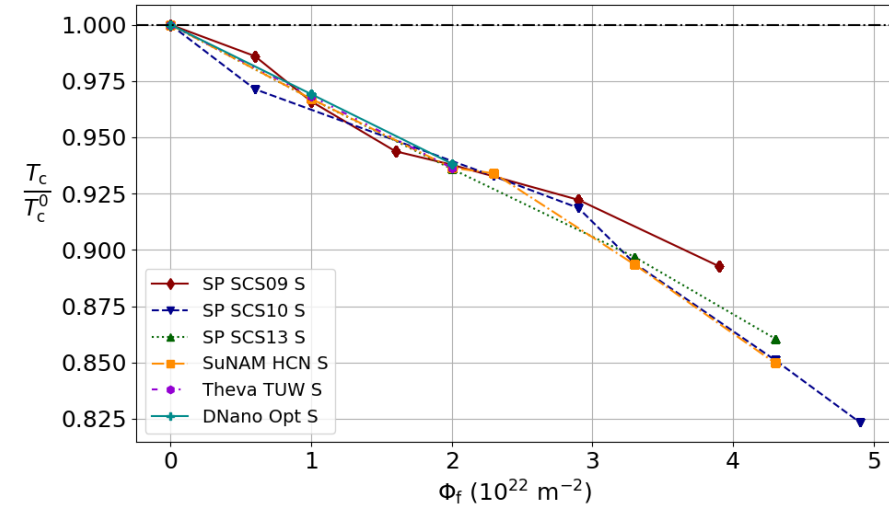


# Pair breaking in cuprates

- Scattering is pair breaking in cuprates.
- $T_c$  degrades with increasing resistivity.



R. J. Radtke et al., PRB **48** (1993) 653



R. Unterrainer et al., SuST **37** (2024) 105008

- Resistivity not easily accessible in coated conductors
- Disorder parameter,  $D$ : decrease of  $T_c$  ( $D = T_c^0 - T_c$ )
- $D \propto \tau^{-1}$
- $D \propto \phi$  (different slope for different particles)



# Scattering in cuprates

- BCS coherence length:  $\xi_0 = 0.15 \frac{\hbar v_F}{k_B T_c}$  (d-wave) increases.
- $\alpha = \frac{\xi_0}{l}$  increases stronger.
- Change (increase?) of coherence length:  $\xi = \frac{\xi_0}{\sqrt{1 + \frac{\xi_0}{l}}}$ .
- Magnetic penetration depth increases stronger:  $\lambda = \sqrt{\frac{m_e}{\mu_0 n_s e^2}} = \lambda_L \sqrt{1 + \frac{\xi_0}{l}}$ .
  - Superfluid density  $n_s \propto \frac{1}{\lambda^2} = \frac{1}{1 + \alpha}$  is stronger reduced.
  - Pair breaking current density,  $J_d = \frac{\phi_0}{3\sqrt{3}\mu_0\pi\lambda^2\xi}$ , decreases stronger.
- Decrease of depairing current density with  $D(T_c)$ :  $J_d(D) = \frac{\phi_0}{3\sqrt{3}\mu_0\pi\lambda_L^2\xi_0(D)\sqrt{1 + \alpha(D)}}$



# Change in superfluid density

$$\frac{n_s}{n_s^p} = \frac{\lambda_p^2}{\lambda^2} = \frac{1 + \alpha_p}{1 + \alpha} \approx \frac{\alpha_p}{\alpha} = \frac{\xi_0^p l}{l_p \xi_0} = \frac{\rho_n^p T_c}{T_c^p \rho_n}$$

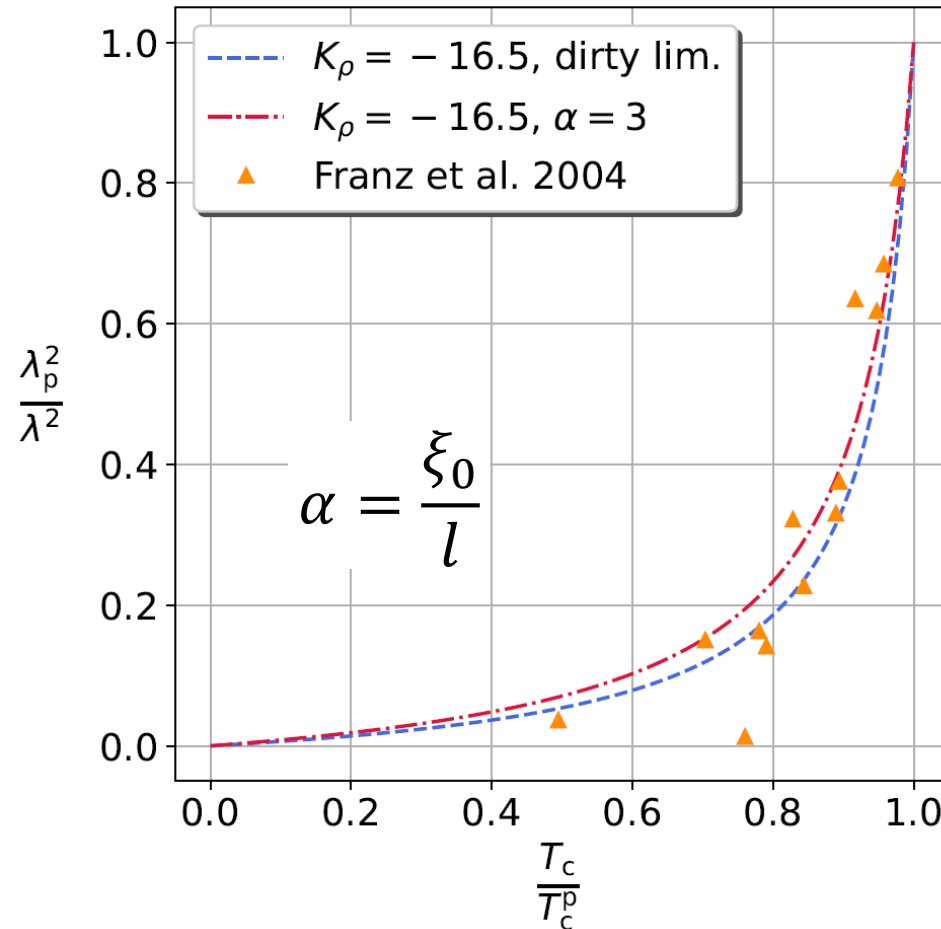
**Our experimental data:**

$$T_c = T_c^p - \beta \phi, \rho_n = \rho_n^p + \gamma \phi$$

$$K_\rho^{-1} = -\frac{\beta \rho_n^p}{\gamma T_c^p} = -\frac{\rho_n^p}{T_c^p} \frac{\partial T_c}{\partial \rho}$$

$\frac{\partial T_c}{\partial \rho}$  universal for optimally doped RE-123?

- Theory:  $-(0.7-1.2) \text{ K}/\mu\Omega\text{cm}$   
R. J. Radtke et al., PRB 48 (1993) 653
- **Fast neutrons, Y-123 films:**  $\sim -0.1 \text{ K}/\mu\Omega\text{cm}$
- e<sup>-</sup> irradiated YBCO sc:  $\sim -0.35 \text{ K}/\mu\Omega\text{cm}$   
Rullier-Albenque et al., PRL 91 (2003) 047001
- Zn-doped Y-123 sc:  $\sim -0.28 \text{ K}/\mu\Omega\text{cm}$   
T.R. Chen et al., PRL 67 (1991) 2088



**Experimental data from literature**

M. Franz et al. PRB 56 (1997) 7882



# Summary scattering

**Any** defect decreases the mean free path of the charge carrier,  $l$ .

- Normal conductors
  - Increase in normal state resistivity  $\rho_n = \frac{m_e v_F}{n e^2 l}$
- Superconductors
  - Decrease of coherence length in conventional sc:  $\xi = \frac{\xi_0}{\sqrt{1 + \frac{\xi_0}{l}}} \approx \sqrt{\xi_0 l}$   
 Increase of  $\xi$  because of increase of  $\xi_0$  (cuprates)
  - Increase of magnetic penetration depth:  $\lambda = \lambda_L \sqrt{1 + \frac{\xi_0}{l}}$   
 → Decrease of superfluid density  $\propto \frac{1}{\lambda^2}$   
 → Decrease of depairing current  $\propto \frac{1}{\lambda^2 \xi}$
- Relevant parameter:  $\tau^{-1}$  ( $\rightarrow \rho_n, T_c$ )
- **Most efficient:** large number of small defects (dpa in superconducting matrix).



# Modelling changes in $I_c$

## Flux pinning



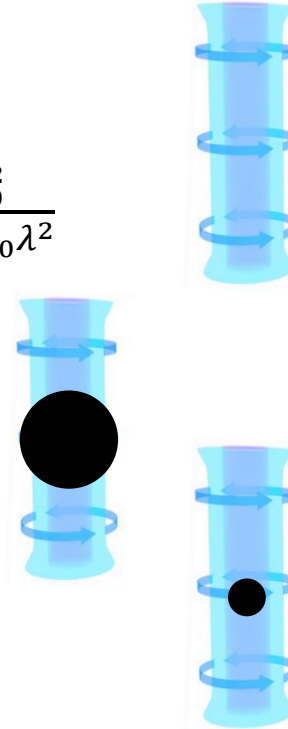
# Flux pinning

- Condensation energy density:  $E_c = \frac{\phi_0^2}{16\pi^2\mu_0\lambda^2\xi^2}$
- Energy of vortex core per meter:  $E_{\text{core}} = E_c \pi\xi^2 = \frac{\phi_0^2}{16\pi\mu_0\lambda^2}$

## 1. Normal conducting/insulating defects ( $\Delta T_c$ -pinning)

a. Large defects:  $r_D > \xi$ :  $E_{\text{pin}} \cong E_c \pi\xi^2 2r_D = \frac{\phi_0^2 r_D}{8\pi\mu_0\lambda^2}$

b. Small defects:  $r_D < \xi$ :  $E_{\text{pin}} = E_c \frac{4\pi r_D^3}{3} = \frac{\phi_0^2 r_D^3}{12\pi\mu_0\lambda^2\xi^2}$



## 2. Tiny defects, no suppression of $E_c$ ( $\Delta l$ -pinning): vortex core shrinks

- Critical state:  $F_p = F_L = |J_c \times B|$ , force balance,  $f_{\text{pin}} = \frac{E_{\text{pin}}}{\xi}$

**Any defect contributes to pinning!**



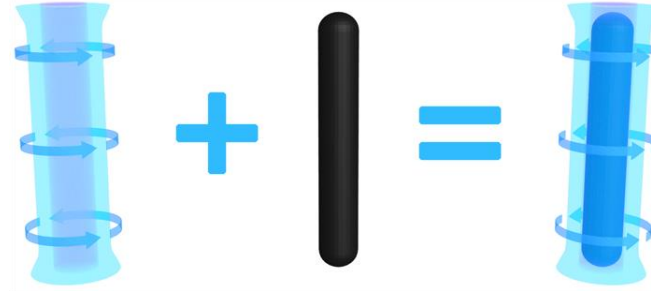
# Pinning efficiency

- Thermodynamic limit: depairing current density

$$J_d = \frac{\phi_0}{3\pi\sqrt{3}\mu_0\lambda^2\xi}$$

- Energy of vortex core per meter:  $E_{\text{core}} = \frac{\phi_0^2}{16\pi\mu_0\lambda^2}$

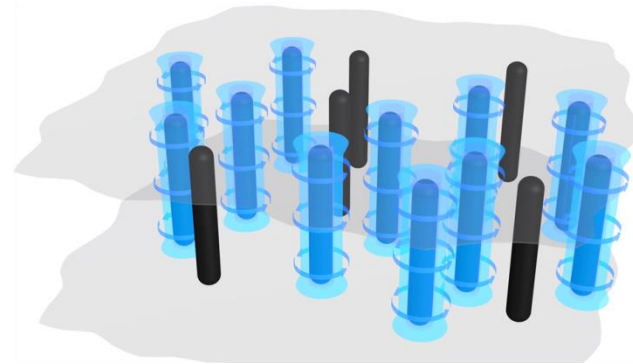
$$f_p^{\text{max}} = \frac{E_{\text{core}}}{\xi} = \frac{\phi_0^2}{16\pi\mu_0\lambda^2\xi}$$



- $J_c^{\text{max}} = \frac{f_p^{\text{max}}}{\phi_0} = \frac{\phi_0}{16\pi\mu_0\lambda^2\xi} = \frac{3\sqrt{3}}{16}J_d \approx 0.32J_d$

- $\eta_{\text{pin}} = \frac{J_c}{J_d}$  ... pinning efficiency

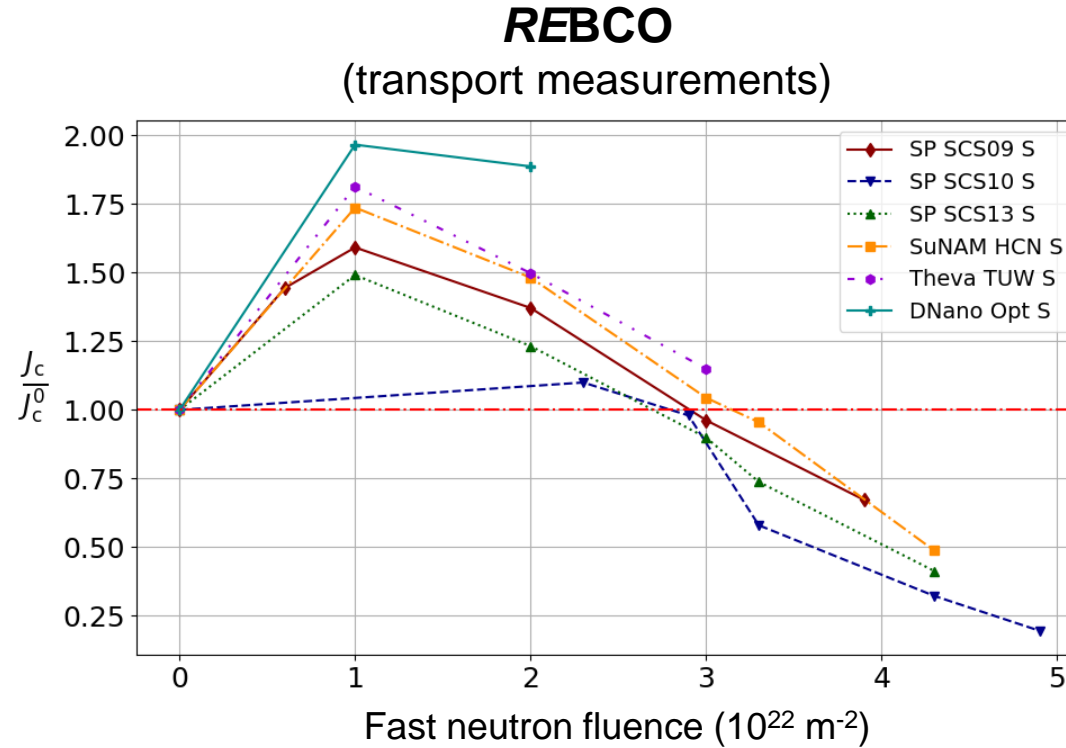
- $\eta_{\text{pin,max}} \approx 32\%$



- Large defects  $r_D \geq \xi$  needed for a large  $\eta_{\text{pin}}$  (although any defect can contribute to pinning)



# Change in critical current density



R. Unterrainer et al.,  
SuST **37** (2024) 105008

Improved pinning vs. loss in superfluid density

Separation of the two contributions:  $J_c = \eta_{\text{pin}} J_d(D)$ ,  $\eta_{\text{pin}} < 1$ .....pinning efficiency



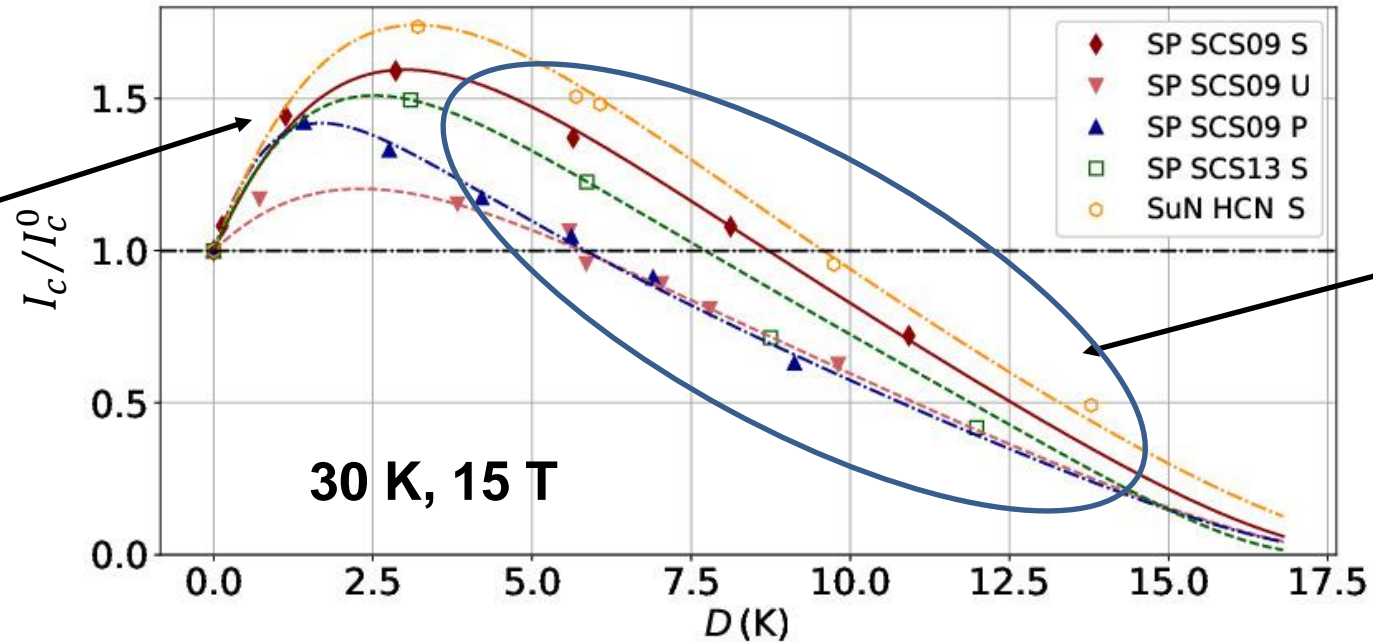
# Universal degradation



Pinning efficiency  $\eta_{pin}$  increases

Large defects?  
Good dpa?

$$J_c = \eta_{pin} J_d(D)$$



$J_d$  decreases

Predictable from changes in  $T_c$  and  $\rho_n$ .

Small defects?  
Bad dpa?

Very similar degradation behavior:

- Same tape (SP SCS09) different irradiation techniques
  - Fast and thermal neutrons (U)
  - Fast neutrons (S)
  - 1.2 MeV protons (P)
- Different tapes (S): SP SCS09, SuN HCN, SP SCS13 (artificial pinning centers)

M. Eisterer et al., arXiv:2409.01376v1

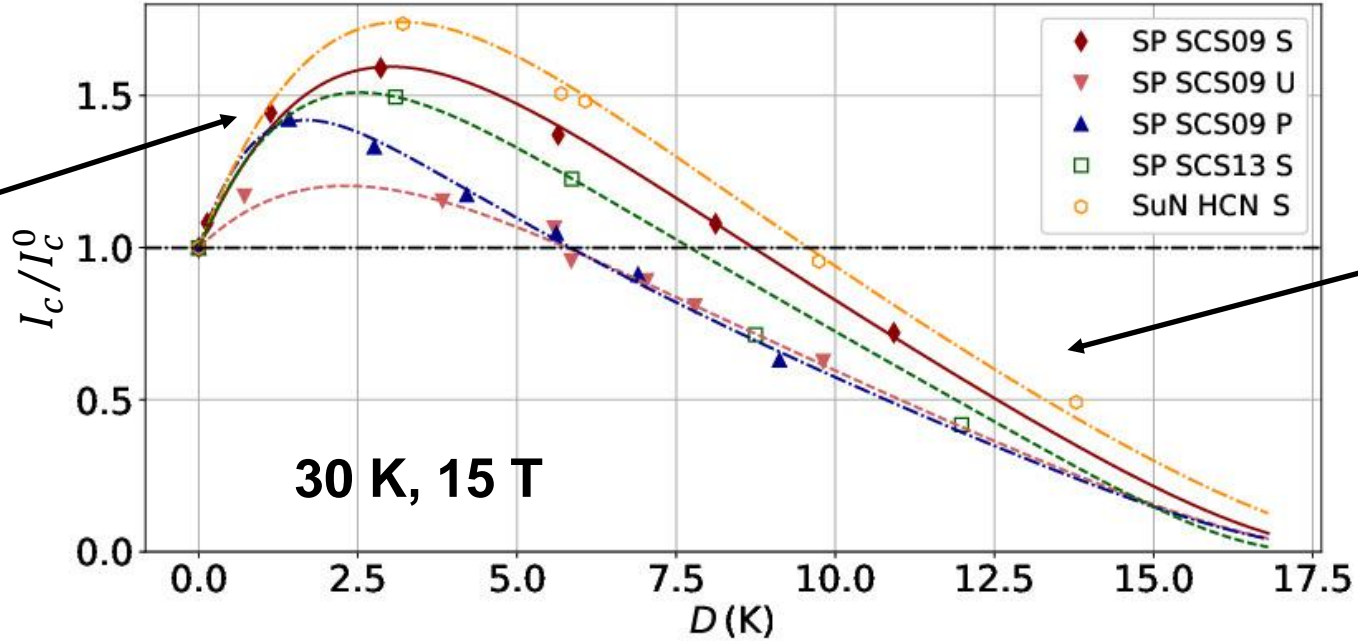


# Change of critical current

Separation of contributions from enhanced pinning and scattering:  $J_c \propto \eta_{pin} J_d$

Pinning efficiency  
 $\eta_{pin}$  increases

Mainly caused by  
large defects



$J_d$  decreases

Resulting from  
scattering (small  
defects)

$$\frac{I_c}{I_c^0} = \frac{\eta_{pin}}{\eta_{pin}^0} \frac{J_d}{J_d^0} \frac{A_{creep}}{A_{creep}^0} =: \frac{\eta_{pin}}{\eta_{pin}^0} F_D(D) \quad F_D \dots \text{degradation function}$$

M. Eisterer et al., arXiv:2409.01376v1

$$F_D = \sqrt{\frac{(\alpha_p + 1)t_c^3}{\alpha_p (1 - K_\rho(1 - t_c)) + t_c} \left( \frac{E_{crit}}{\sqrt{\phi_0 B v_0}} \right)^{\frac{1}{n} - \frac{1}{n_p}}}$$

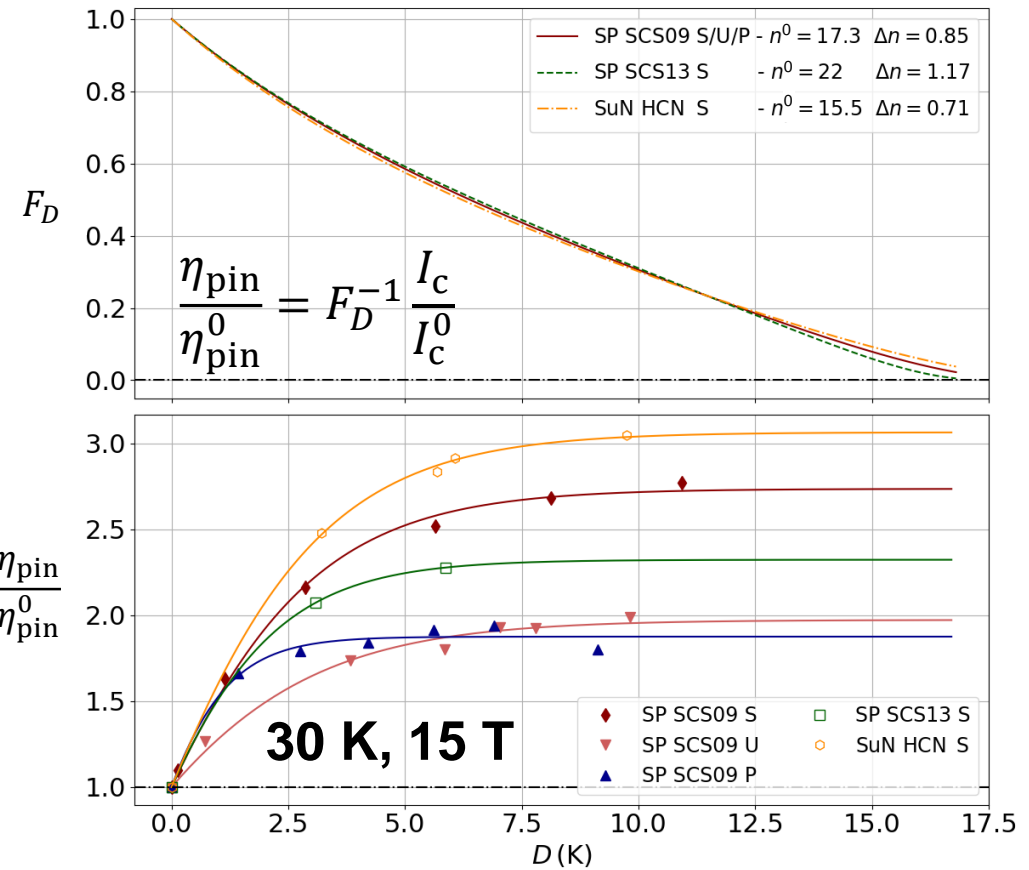
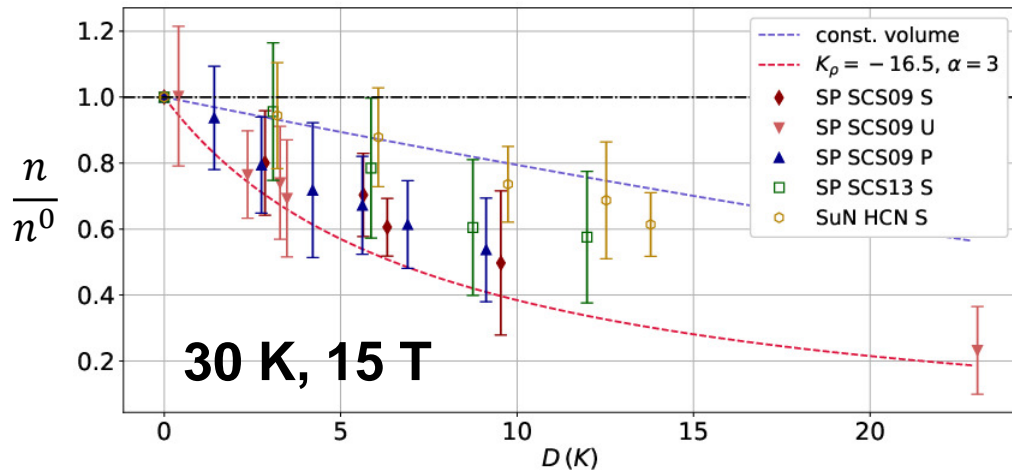
$$t_c = \frac{T_c}{T_{c,p}} \quad \alpha_p = \frac{\xi_{0,p}}{l_p}$$



# Degradation function - pinning contribution

Parameters in  $F_D$

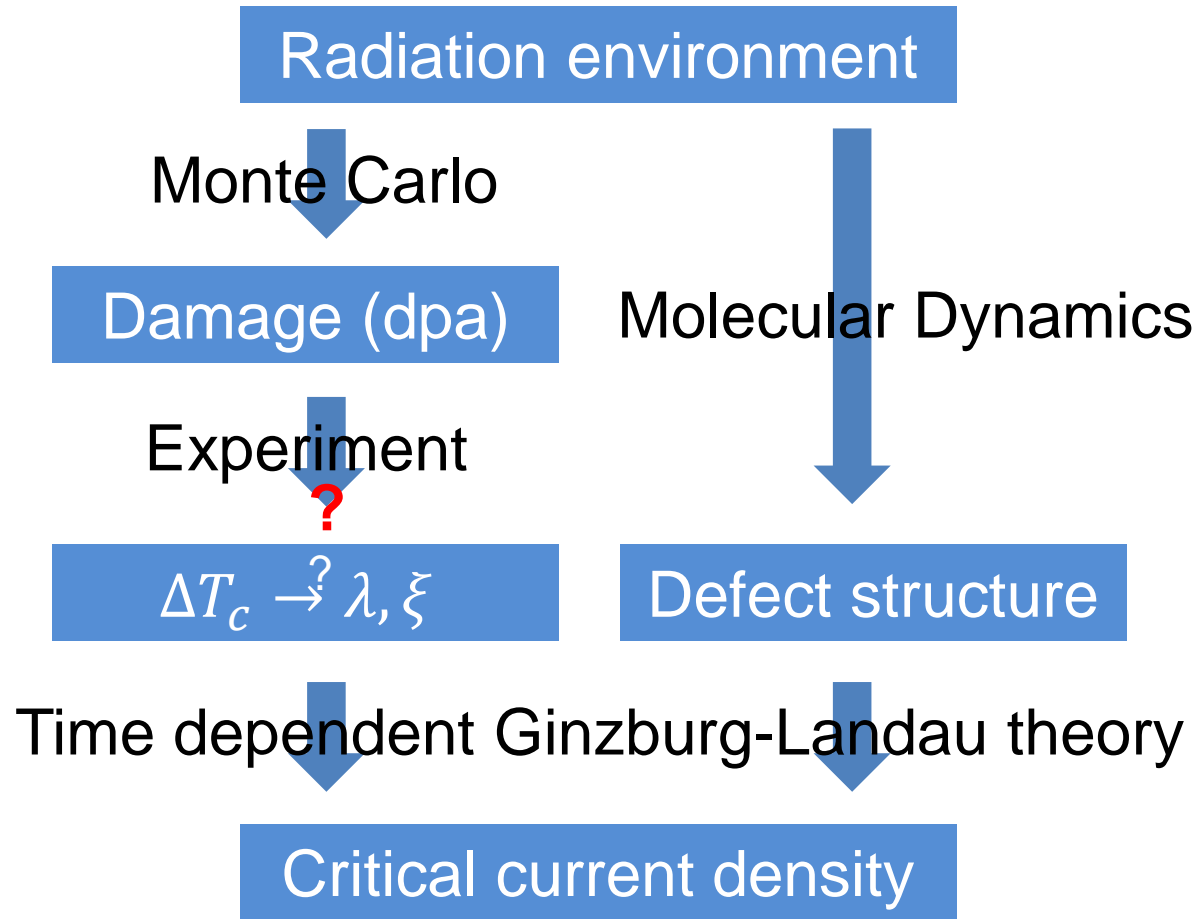
- $\alpha_p = \frac{\xi_0^0}{l_0}$  (fixed to 3, weak influence)
- $K_\rho = \frac{T_c^0}{\rho_n^0} \frac{\partial \rho_n}{\partial T_c} \approx -16.5$   
(experimental value, thin film)
- $n$ -value,  $U \propto I^n$   
linear fit to the experimental values  
(sample dependent)



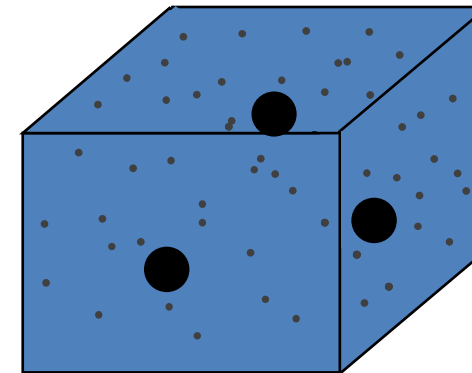
- Strong increase near  $D = 0$ .
- Saturation at large  $D$ .
- $\eta_{pin,max}$  enough for decreasing branch.



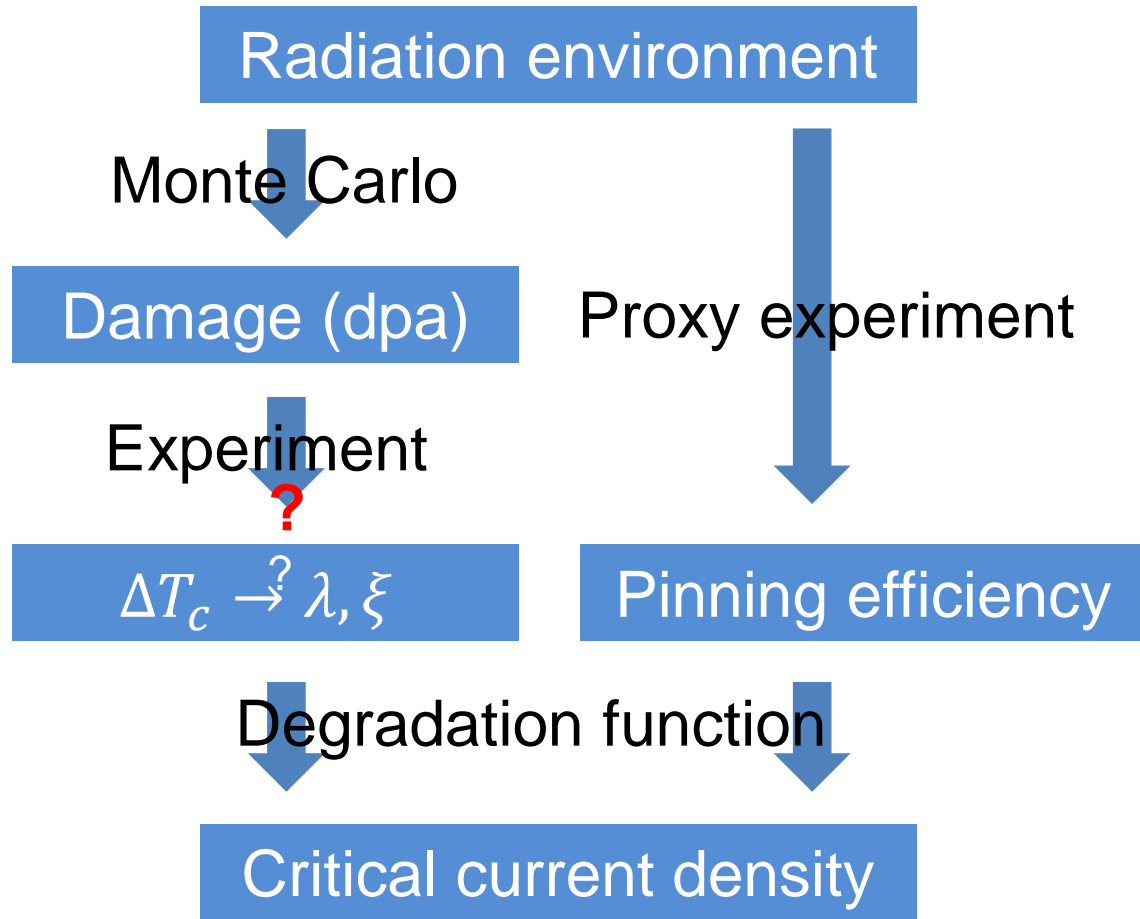
# The experimental/modelling path



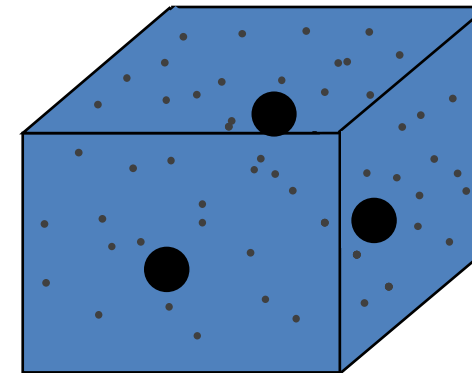
- Scattering rate is the key parameter for the degradation of HTS.
  - Additional parameters?
    - Doping level
    - Strain
- Change in pinning easier to handle?
  - Finding a proxy feasible?
- Damage parameter is needed.
  - Prediction of  $\tau^{-1}$  or  $\Delta T_c$



# The experimental/modelling path



- Scattering rate is the key parameter for the degradation of HTS.
  - Additional parameters?
    - Doping level
    - Strain
- Change in pinning easier to handle?
  - Finding a proxy feasible?
- Damage parameter is needed.
  - Prediction of  $\tau^{-1}$  or  $\Delta T_c$



# Conclusions

- Predicting the property changes in HTS because of the operation in a specific radiation environment is a difficult task.
  - Competing effects:
    - Degradation due to scattering (small defects)
    - Improvement of pinning (large defects)
- Only a combined approach (experiment+modelling) seems feasible.
- Prediction of scattering rate is key
  - Damage parameter?
- Change of flux creep?
- Change in pinning: Only saturation value of  $\eta_{pin}$  is needed?
  - Benchmarking experiments with proxy particles.



I hope you disagree with some points or have some other suggestions so that we have a vivid discussion!



# Points to think of

- Prediction of change in flux pinning
- Prediction of change in  $T_c$
- Is it possible to tune the radiation sensitivity?
- Is the change of  $T_c$  with resistivity universal? Why not?
- Is  $\frac{T_c}{\rho_n}$  a reliable prediction for the (change of) superfluid density?
- What is missing in modelling?
- What is missing from experiments?
- Which benchmarking experiments are missing/needed?



Just in case.....



# Scattering in conventional (s-wave) superconductors

(Non-magnetic) Scattering is not pair breaking in isotropic conventional superconductors.

→ Transition temperature does not change.

→ Condensation energy:  $E_c = \frac{\phi_0^2}{16\pi^2\mu_0\lambda^2\xi^2}$  does not change.

- Gorkov-Goodman relations:  $\kappa = \frac{\lambda}{\xi} = \kappa_0 + 2.37 \cdot 10^6 \sqrt{\gamma_n} \rho_0 = \kappa_0 \left(1 + \frac{\xi_0}{l}\right)$

→ Upper critical field increases:  $B_{c2} = B_{c2}^{\rho_0 \rightarrow 0} + 2.37 \cdot 10^6 \sqrt{\gamma_n} \rho_0 = B_{c2}^{\rho_0 \rightarrow 0} \left(1 + \frac{\xi_0}{l}\right)$

→ Superconducting coherence length decreases:  $\xi = \frac{\xi_0}{\sqrt{1 + \frac{\xi_0}{l}}} \quad (\approx \sqrt{\xi_0 l})$

- Isotropic conventional superconductors

→ Magnetic penetration depth increases:  $\lambda = \sqrt{\frac{m_e}{\mu_0 n_s e^2}} = \lambda_L \sqrt{1 + \frac{\xi_0}{l}}$

→ Superfluid density  $n_s \propto \frac{1}{\lambda^2}$  is reduced.

→ Pair breaking current density,  $J_d = \frac{\phi_0}{3\sqrt{3}\mu_0\pi\lambda^2\xi}$ , decreases.



# Modelling changes in $I_c$

## Flux pinning



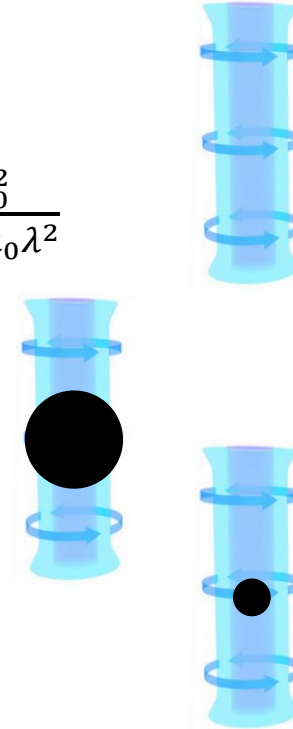
# Flux pinning

- Condensation energy density:  $E_c = \frac{\phi_0^2}{16\pi^2\mu_0\lambda^2\xi^2}$
- Energy of vortex core per meter:  $E_{core} = E_c \pi\xi^2 = \frac{\phi_0^2}{16\pi\mu_0\lambda^2}$

## 1. Normal conducting/insulating defects ( $\Delta T_c$ -pinning)

a. Large defects:  $r_D > \xi$ :  $E_{pin} \cong E_c \pi\xi^2 2r_D = \frac{\phi_0^2 r_D}{8\pi\mu_0\lambda^2}$

b. Small defects:  $r_D < \xi$ :  $E_{pin} = E_c \frac{4\pi r_D^3}{3} = \frac{\phi_0^2 r_D^3}{12\pi\mu_0\lambda^2\xi^2}$



## 2. Tiny defects, no suppression of $E_c$ ( $\Delta l$ -pinning): vortex core shrinks

- Critical state:  $F_p = F_L = |J_c \times B|$ , force balance.
- $f_{pin} = \frac{E_{pin}}{\xi}$



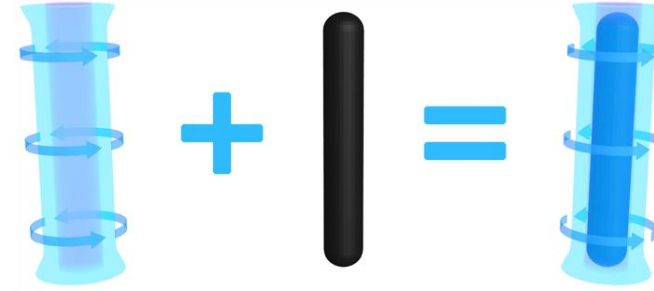
# Pinning efficiency

- Thermodynamic limit: depairing current density

$$J_d = \frac{\phi_0}{3\pi\sqrt{3}\mu_0\lambda^2\xi}$$

- Energy of vortex core per meter:  $E_{\text{core}} = \frac{\phi_0^2}{16\pi\mu_0\lambda^2}$

$$f_p^{\text{max}} = \frac{E_{\text{core}}}{\xi} = \frac{\phi_0^2}{16\pi\mu_0\lambda^2\xi}$$



- Critical state:  $F_p = F_L = |J_c \times B|$

- Highest possible pinning force per vortex and unit length: cylindrical defect with  $r_D \geq \xi$

- Force balance for one vortex ( $B \perp J_c$ ):  $f_L = f_p$

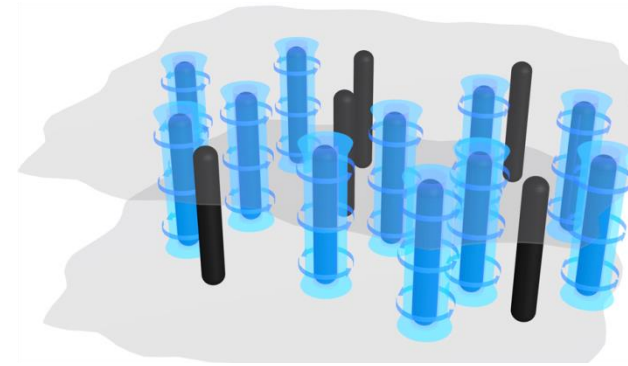
$$f_L = \iint F_L dA = \iint J_c \times B dA = J_c \phi_0 \leq f_p^{\text{max}} = \frac{\phi_0^2}{16\pi\mu_0\lambda^2\xi}$$

- $J_c^{\text{max}} = \frac{f_p^{\text{max}}}{\phi_0} = \frac{\phi_0}{16\pi\mu_0\lambda^2\xi} = \frac{3\sqrt{3}}{16} J_d \approx 0.32 J_d$

- $\eta_{\text{pin}} = \frac{J_c}{J_d}$  ... pinning efficiency

- $\eta_{\text{pin,max}} \approx 32\%$

- Large defects  $r_D \geq \xi$  needed for a large  $\eta_{\text{pin}}$  (although any defect can contribute to pinning)



# Change in superfluid density (Homes's Law)

$$\lambda = \lambda_L \sqrt{\frac{\xi_0}{l}} \text{ with the BCS relation } \xi_0 = 0.18 \frac{\hbar v_f}{k_B T_c}, \rho_n = \frac{m_e v_f}{ne^2 l} \text{ and } \lambda_L = \sqrt{\frac{m_e}{\mu_0 n e^2}}$$

$$\frac{1}{\lambda^2 - \lambda_L^2} = \frac{\mu_0 k_B T_c}{0.18 \hbar \rho_n} = \frac{1}{\lambda^2} \frac{\mu_0 k_B}{0.18 \hbar} = 9.14 \cdot 10^5 \text{ } \Omega \text{m}^{-1} \text{K}^{-1}$$

## Our experimental data:

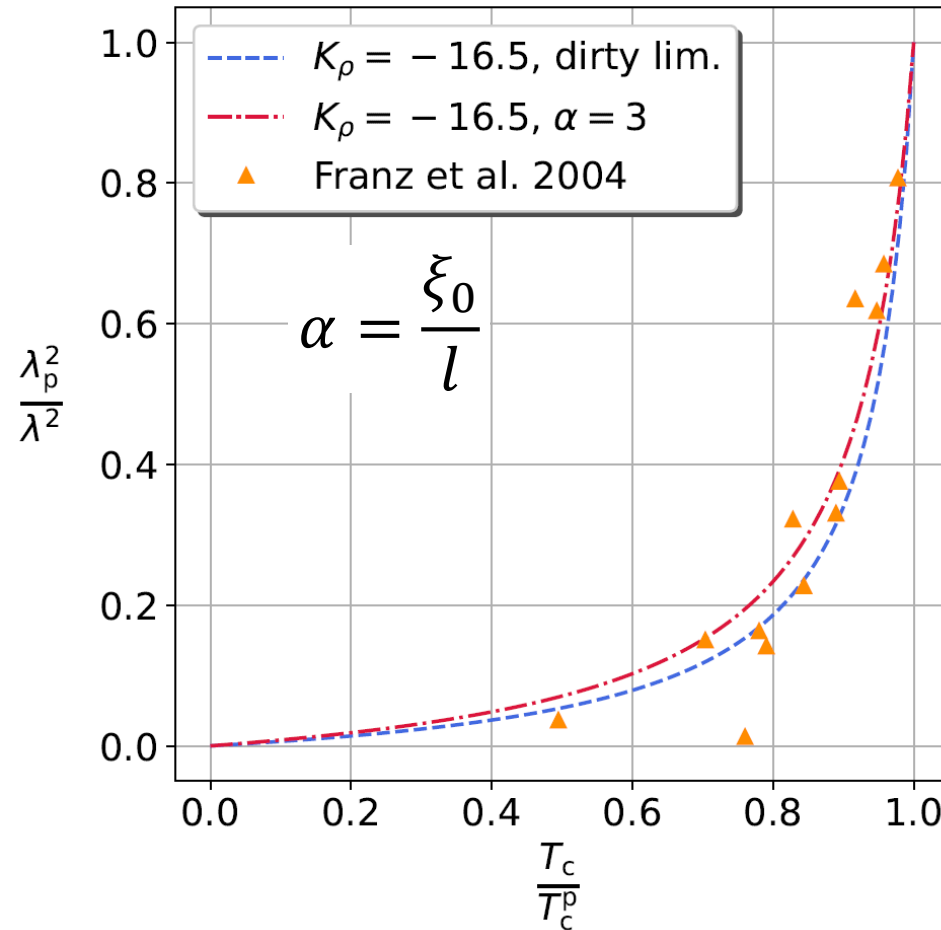
$$T_c = T_c^{unirr} - \beta \phi, \rho = \rho_{unirr} + \alpha \phi$$

$$K_\rho = -\frac{\alpha T_c^{unirr}}{\beta \rho_{unirr}} = \frac{T_c^{unirr}}{\rho_{unirr}} \frac{\partial \rho}{\partial T_c}$$

## Experimental data from literature:

M. Franz et al. PRB 56 (1997) 7882

**Suitable prediction of the change in superfluid density!**



# Modelling changes in $I_c$

## Resulting changes

